FAIRCHILD

SEMICONDUCTOR TM

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FSAV430 Low Voltage Ultra Low Power High Bandwidth (1.1GHz) Quad SPDT Video Switch

General Description

FSAV430 is a high performance Quad SPDT (2-to-1 multiplexer/demultiplexer) video switch designed specifically for switching high definition YPbPr and computer RGB (up to UXGA) signals. The bandwidth of this device is 1.1GHz (Typ) which allows signals to pass with minimal edge and phase distortion. Image integrity is maintained with low crosstalk, high OFF-Isolation and low differential gain and phase. The low On Resistance (4.5 Ω typical) minimizes signal insertion loss. Low voltage operation (3V), low power consumption (1uA maximum) and small scale packaging (including leadless DQFN) make this device ideal for a broad range of applications.

Features

- -50dB OFF Isolation at 10MHz
- -75dB non-adjacent channel crosstalk at 10MHz
- 4.5Ω typical On Resistance (R_{ON})
- –3dB bandwidth: 1.1GHz
- Low power consumption (1uA max)
- Control input: TTL compatible
- Bidirectional operation

Applications

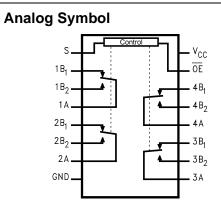
- RGB Video Switch in LCD, plasma and projection displays
- DVD-RW

Ordering Code:

Order Number	Package Number	Package Description				
FSAV430BQX (Note 1) (Preliminary)	MLP016E	16-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC MO-241 2.5 x 3.5mm				
FSAV430QSC	MQA16	16-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide				
FSAV430MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide				
	ble in Tape and Reel. Spe kage available in Tape an	ecify by appending suffix letter "X" to the ordering code. d Reel only.				

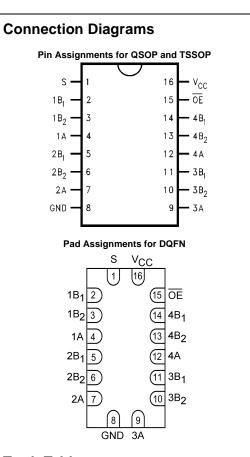
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Pin Descriptions

Pin Name	Description		
OE	Bus Switch Enable		
S	Select Input		
A	Bus A		
B ₁ -B ₂	Bus B		



Truth Table

s	OE	Function
х	Н	Disconnect
L	L	$A=B_1$
н	L	$A = B_2$

Absolute Maximum Ratings(Note 2)

Recommended Operating

Supply Voltage (V _{CC})	-0.5V to +4.6V
DC Switch Voltage (V _S)	–0.5V to V_{CC} +0.05V
DC Input Voltage (VIN) (Note 3)	-0.5V to +4.6V
DC Input Diode Current (I_{IK}) $V_{IN} < 0V$	–50 mA
DC Output (I _{OUT}) Sink Current	128 mA
DC V _{CC} /GND Current (I _{CC} /I _{GND})	±100 mA
Storage Temperature Range (T _{STG})	-65°C to +150 °C
ESD	
Human Body Model	4kV

V	Conditions (Note 4)	-
V	Power Supply Operating (V_{CC})	3.0V to 3.6V
V	Input Voltage (V _{IN})	0V to V_{CC}
Ą	Output Voltage (V _{OUT})	0V to V _{CC}
Ą	Input Rise and Fall Time (t _r , t _f)	
Ą	Switch Control Input	0 ns/V to 5 ns/V
С	Switch I/O	0 ns/V to DC
	Free Air Operating Temperature (T _A)	–40 °C to +85 °C

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 3: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Note 4: Unused control inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

	Vee	T _A =	-40 °C to +	85 °C		
Parameter	(V)	Min	Typ (Note 5)	Max	Units	Conditions
Analog Signal Range		0		2.0	V	
Clamp Diode Voltage	3.0			-1.2	V	$I_{IN} = -18 \text{ mA}$
HIGH Level Input Voltage	3.0 - 3.6	2.0			V	
LOW Level Input Voltage	3.0 - 3.6			0.8	V	
Input Leakage Current	3.6			±1.0	μΑ	$0 \le V_{IN} \le 3.6V$
OFF-STATE Leakage Current	3.6			±1.0	μA	$0 \le A, B \le V_{CC}$
Switch On Resistance (Note 6)	3.0		5.0	7.0	Ω	$V_{IN} = 1.0V$ $R_I = 75 \ \Omega, \ I_{ON} = 13 \ mA$
	3.0		4.5	6.0	Ω	$V_{IN} = 2.0V$ $R_I = 75 \ \Omega, \ I_{ON} = 26 \ mA$
On Resistance Flatness (Note 7)	3.0		1.0		Ω	$I_{OUT} = 13 \text{ mA}, V_{IN} = 0 \text{ to } V_{CC}$
Quiescent Supply Current	3.6			1.0	μΑ	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$
Increase in I _{CC} per Input	3.6			30.0	uA	One Input at 3.0V Other Inputs at V _{CC} or GND
	Analog Signal Range Clamp Diode Voltage HIGH Level Input Voltage LOW Level Input Voltage Input Leakage Current OFF-STATE Leakage Current Switch On Resistance (Note 6) On Resistance Flatness (Note 7) Quiescent Supply Current	(V) Analog Signal Range Clamp Diode Voltage 3.0 HIGH Level Input Voltage 3.0 - 3.6 LOW Level Input Voltage 3.0 - 3.6 Input Leakage Current 3.6 OFF-STATE Leakage Current 3.6 Switch On Resistance (Note 6) 3.0 On Resistance Flatness (Note 7) 3.0 Quiescent Supply Current 3.6	Parameter V _{CC} (V) Min Analog Signal Range 0 Clamp Diode Voltage 3.0 HIGH Level Input Voltage 3.0 - 3.6 LOW Level Input Voltage 3.0 - 3.6 Input Leakage Current 3.6 OFF-STATE Leakage Current 3.6 Switch On Resistance (Note 6) 3.0 On Resistance Flatness (Note 7) 3.0 Quiescent Supply Current 3.6	ParameterV _{CC} (V)Typ (Note 5)Analog Signal Range0Clamp Diode Voltage3.0HIGH Level Input Voltage3.0 - 3.6LOW Level Input Voltage3.0 - 3.6Input Leakage Current3.6OFF-STATE Leakage Current3.6Switch On Resistance (Note 6)3.0Jon Resistance Flatness (Note 7)3.0Quiescent Supply Current3.6	Parameter (V) Min Typ (Note 5) Max Analog Signal Range 0 2.0 Clamp Diode Voltage 3.0 -1.2 HIGH Level Input Voltage 3.0 - 3.6 2.0 LOW Level Input Voltage 3.0 - 3.6 0 4.5 Input Leakage Current 3.6 ±1.0 5.0 7.0 OFF-STATE Leakage Current 3.6 5.0 7.0 Switch On Resistance (Note 6) 3.0 4.5 6.0 On Resistance Flatness (Note 7) 3.0 1.0 1.0	ParameterV_{CC} (V)Typ (Note 5)UnitsMinTyp (Note 5)MaxUnitsAnalog Signal Range02.0VClamp Diode Voltage3.00-1.2VHIGH Level Input Voltage3.0 - 3.62.0VLOW Level Input Voltage3.0 - 3.60.8VInput Leakage Current3.6 ± 1.0 μA OFF-STATE Leakage Current3.6 ± 1.0 μA Switch On Resistance (Note 6)3.05.07.0 Ω On Resistance Flatness (Note 7)3.01.0 Ω Quiescent Supply Current3.61.0 μA

Note 5: Typical values are at $T_A=+25^\circ C$

Note 6: Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B) pins.

Note 7: Flatness is defined as the difference between the maximum and minimum value On Resistance over the specified range of conditions.

FSAV430

AC Electrical Characteristics

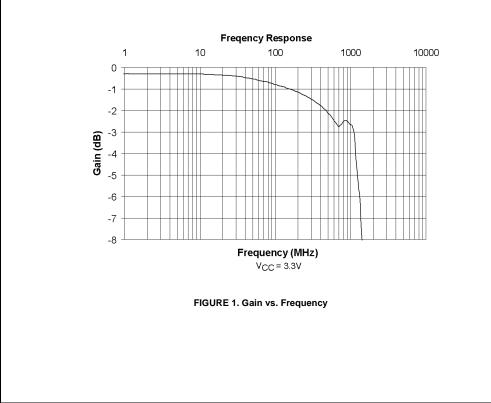
Symbol	Parameter	V _{CC} (V)	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				Figure	
			Min	Typ (Note)	Max	Units	Conditions	Number
t _{ON}	Turn ON Time S-to-Bus A	3.0 to 3.6		4.8	7.0	ns	B _n = 2.0V	Figures
	Output Enable Time OE-to-A	3.0 to 3.6		4.5	6.8	113		8, 9
t _{OFF}	Turn OFF Time S-to-Bus A	3.0 to 3.6		2.2	4.0	ns	P 2.01/	Figures
	Output Disable Time OE-to-A	3.0 to 3.6		2.2	4.0	115	$B_n = 2.0V$	8, 9
DG	Differential Gain	3.0 to 3.6		0.2		%	$R_L = 75\Omega$, f= 3.58MHz	Figures 2, 3
DP	Differential Phase	3.0 to 3.6		0.1		Degree	$R_L = 75\Omega$, f= 3.58MHz	Figures 2, 3
O _{IRR}	Non-Adjacent OFF-Isolation	3.0 to 3.6		-50.0		dB	$f = 10MHz, R_L = 75\Omega$	Figures 4, 10
X _{TALK}	Non-Adjacent Channel Crosstalk	3.0 to 3.6		-75.0		dB	$R_L = 75\Omega$, f= 10MHz	Figures 5, 11
BW	-3dB Bandwidth	3.0 to 3.6		1.1		GHz	$R_L = 75\Omega$	Figures 1, 12

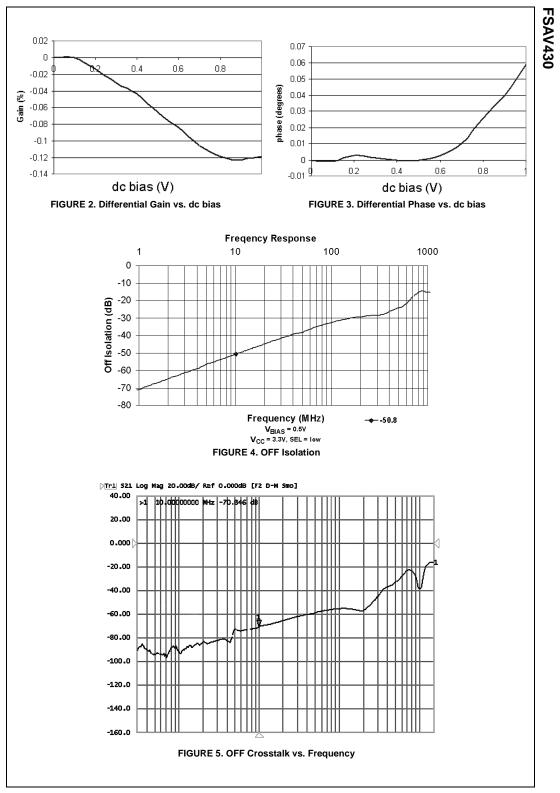
Note 8: Typical values are at V_{CC} = 3.3V and T_A = +25 $^{\circ}C$

Capacitance

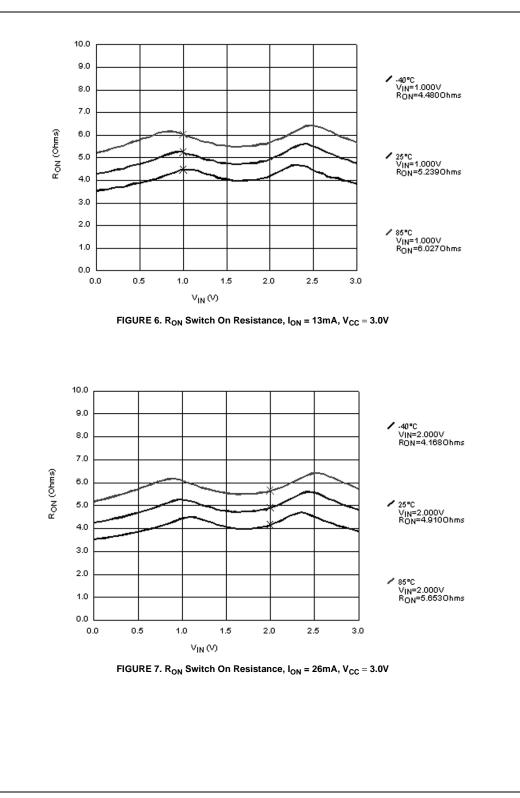
Symbol	Parameter	$T_{A}=-40^{\circ}C$ to $+85^{\circ}C$	Units	Conditions	
Symbol	i arameter	Typ (Note)	Onits	Conditiona	
C _{IN}	Control Pin Input Capacitance	2.5	pF	$V_{CC} = 0V$	
C _{ON}	A/B ON Capacitance	12.0	pF	$V_{CC} = 3.3V, \overline{OE} = 0V$	
C _{OFF}	Port B OFF Capacitance	4.0	pF	V_{CC} and $\overline{OE} = 3.3V$	

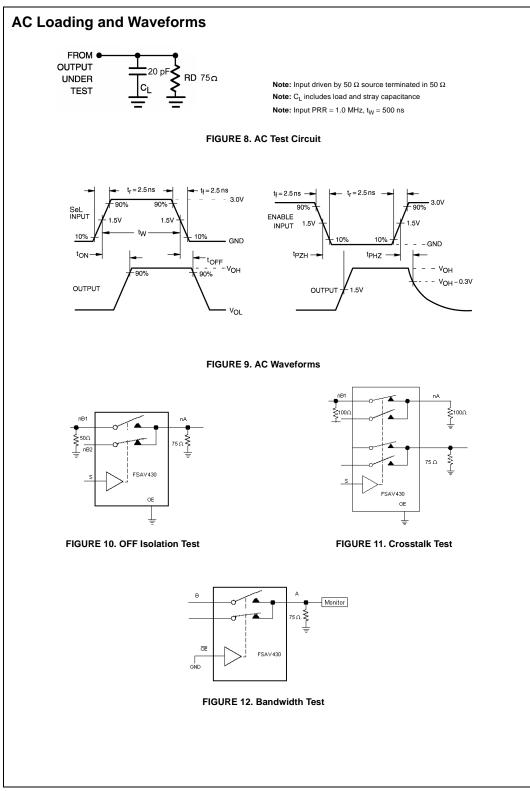
Note 9: Typical values are at $V_{CC}=3.3V$ and $T_A=+25^\circ C$











FSAV430



Tape and Reel Specification

Tape Format for DQFN

Package	Таре	Number	Cavity	Cover Tape	
Designator	Section	Cavities	Status	Status	
	Leader (Start End)	125 (typ)	Empty	Sealed	
BQ/BQX	Carrier	2500/3000	Filled	Sealed	
	Trailer (Hub End)	75 (typ)	Empty	Sealed	

TAPE DIMENSIONS inches (millimeters)

